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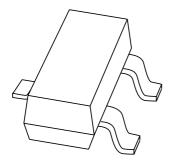
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS

DATA SHEET



BAT17Schottky barrier diode

Product data sheet Supersedes data of 1999 May 26 2003 Mar 25



NXP Semiconductors Product data sheet

Schottky barrier diode

BAT17

FEATURES

- · Low forward voltage
- Small SMD package
- · Low capacitance.

APPLICATIONS

- UHF mixer
- Sampling circuits
- Modulators
- Phase detection.

DESCRIPTION

Planar Schottky barrier diode in a small SOT23 plastic SMD package.

MARKING

| TYPE NUMBER | MARKING CODE ⁽¹⁾ | | |
|-------------|--------------------------------|--|--|
| BAT17 | A3* | | |

Note

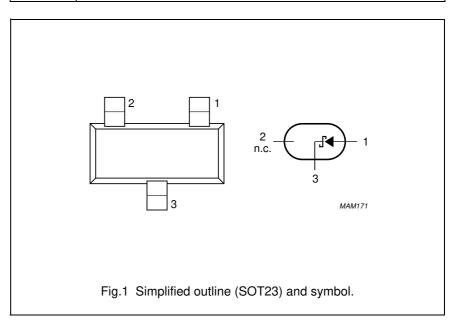
1. * = p: Made in Hong Kong.

* = t: Made in Malaysia.

* = W : Made in China.

PINNING

| PIN | DESCRIPTION |
|-----|---------------|
| 1 | anode |
| 2 | not connected |
| 3 | cathode |



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT |
|------------------|----------------------------|------|------|------|
| V_R | continuous reverse voltage | _ | 4 | V |
| I _F | continuous forward current | _ | 30 | mA |
| T _{stg} | storage temperature | -65 | +150 | °C |
| Tj | junction temperature | _ | 100 | °C |

NXP Semiconductors Product data sheet

Schottky barrier diode

BAT17

ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MAX. | UNIT |
|----------------|--------------------------|---|------|------|
| V _F | forward voltage | see Fig.2 | | |
| | | I _F = 0.1 mA | 350 | mV |
| | | I _F = 1 mA | 450 | mV |
| | | I _F = 10 mA | 600 | mV |
| I _R | reverse current | V _R = 3 V; see Fig.3 | 0.25 | μΑ |
| | | $V_R = 3 \text{ V}; T_{amb} = 60 \text{ °C}; \text{ see Fig.3}$ | 1.25 | μΑ |
| r _D | diode forward resistance | $f = 1 \text{ kHz}; I_F = 5 \text{ mA}$ | 15 | Ω |
| C _d | diode capacitance | f = 1 MHz; V _R = 0; see Fig.4 | 1 | pF |
| F | noise figure | f = 900 MHz; note 1 | 8 | dB |

Note

1. The local oscillator is adjusted for a diode current of 2 mA. IF amplifier noise F_{if} = 1.5 dB; f = 35 MHz.

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------------|---|------------|-------|------|
| R _{th j-a} | thermal resistance from junction to ambient | note 1 | 500 | K/W |

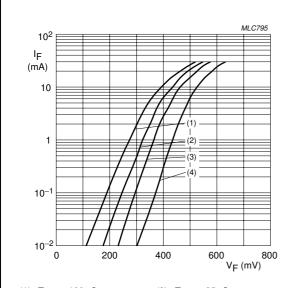
Note

1. Refer to SOT23 standard mounting conditions.

Schottky barrier diode

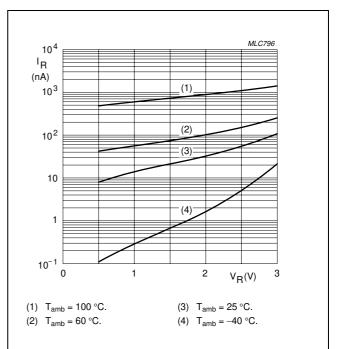
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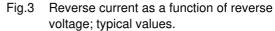
GRAPHICAL DATA

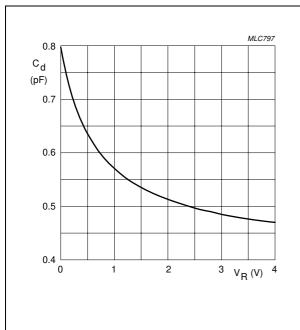


- (1) $T_{amb} = 100 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (2) $T_{amb} = 60 \, ^{\circ}\text{C}$. (4) $T_{amb} = -40 \, ^{\circ}\text{C}$.

Fig.2 Forward current as a function of forward voltage; typical values.







f = 1 MHz; $T_{amb} = 25 \,^{\circ}\text{C}$.

Fig.4 Diode capacitance as a function of reverse voltage; typical values.

NXP Semiconductors Product data sheet

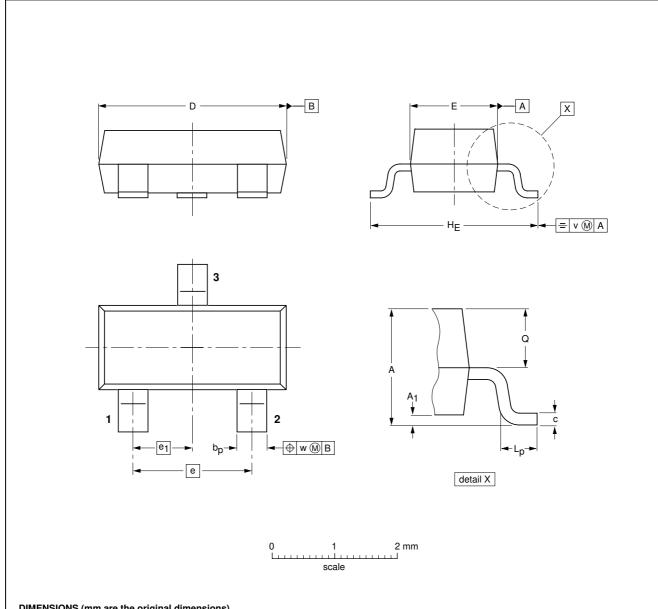
Schottky barrier diode

BAT17

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



DIMENSIONS (mm are the original dimensions)

| UNIT | Α | A ₁ max. | bp | С | D | E | е | e ₁ | HE | Lp | Q | ٧ | w |
|------|------------|---------------------|--------------|--------------|------------|------------|-----|----------------|------------|--------------|--------------|-----|-----|
| mm | 1.1 0.9 | 0.1 | 0.48 0.38 | 0.15 0.09 | 3.0 2.8 | 1.4 1.2 | 1.9 | 0.95 | 2.5 2.1 | 0.45 0.15 | 0.55 0.45 | 0.2 | 0.1 |

| OUTLINE | | REFER | EUROPEAN | ISSUE DATE | | |
|---------|-----|----------|----------|------------|------------|---------------------------------|
| VERSION | IEC | JEDEC | EIAJ | | PROJECTION | ISSUE DATE |
| SOT23 | | TO-236AB | | | | 97-02-28 99-09-13 |

2003 Mar 25 5 NXP Semiconductors Product data sheet

Schottky barrier diode

BAT17

DATA SHEET STATUS

| DOCUMENT STATUS(1) | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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NXP Semiconductors

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Contact information

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